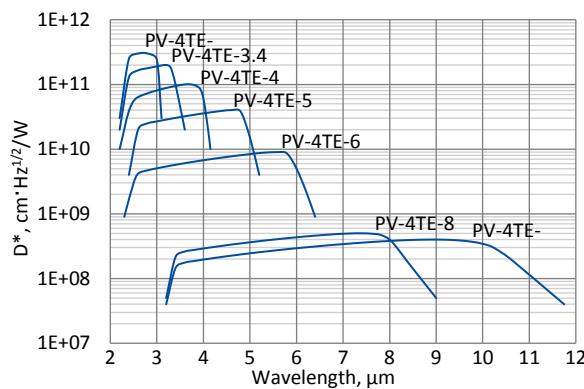


2.12 PV-4TE series

2.12.1 2.0 – 12.0 μm HgCdTe four-stage thermoelectrically cooled photovoltaic detectors

PV-4TE series features four-stage thermoelectrically cooled IR photovoltaic detectors based on sophisticated HgCdTe heterostructures for the best performance and stability. The devices are optimized for the maximum performance at λ_{opt} . Cut-on wavelength can be optimized upon request. Reverse bias may significantly increase response speed and dynamic range. It also results in improved performance at high frequencies, but 1/f noise that appears in biased devices may reduce performance at low frequencies. 3° wedged sapphire (wAl_2O_3) or zinc selenide anti-reflection coated (wZnSeAR) window prevents unwanted interference effects.

Spectral response ($T_a = 20^\circ\text{C}$, $V_b = 0 \text{ mV}$)



Exemplary spectral detectivity, the spectral response of delivered devices may differ.

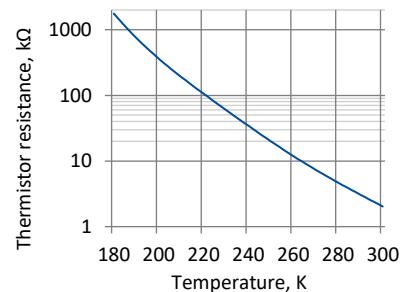
Specification ($T_a = 20^\circ\text{C}$, $V_b = 0 \text{ V}$)

Parameter	Detector type								
	PV-4TE-3	PV-4TE-3.4	PV-4TE-4	PV-4TE-5	PV-4TE-6	PV-4TE-8	PV-4TE-10.6		
Active element material	epitaxial HgCdTe heterostructure								
Optimum wavelength λ_{opt} , μm	3.0	3.4	4.0	5.0	6.0	8.0	10.6		
Detectivity $D^*(\lambda_{\text{peak}})$, $\text{cm}\cdot\text{Hz}^{1/2}/\text{W}$	$\geq 3.0 \times 10^{11}$	$\geq 2.0 \times 10^{11}$	$\geq 1.0 \times 10^{11}$	$\geq 4.0 \times 10^{10}$	$\geq 9.0 \times 10^9$	$\geq 5.0 \times 10^8$	$\geq 4.0 \times 10^8$		
Detectivity $D^*(\lambda_{\text{opt}})$, $\text{cm}\cdot\text{Hz}^{1/2}/\text{W}$	$\geq 1.5 \times 10^{11}$	$\geq 1.0 \times 10^{11}$	$\geq 6.0 \times 10^{10}$	$\geq 1.5 \times 10^{10}$	$\geq 5.0 \times 10^9$	$\geq 4.0 \times 10^8$	$\geq 2.0 \times 10^8$		
Current responsivity $R_i(\lambda_{\text{opt}})$, A/W	≥ 0.5	≥ 0.8	≥ 1.0	≥ 1.3	≥ 1.5	≥ 1.5	≥ 0.5		
Time constant τ , ns	≤ 280	≤ 200	≤ 100	≤ 80	≤ 50	≤ 45	≤ 25		
Resistance-active area product $R\cdot A$, $\Omega\cdot\text{cm}^2$	≥ 300	≥ 20	≥ 8	≥ 0.4	≥ 0.03	≥ 0.0006	≥ 0.0005		
Active element temperature T_{det} , K	~ 195								
Active area A, mm \times mm	0.1×0.1					$0.05 \times 0.05, 0.1 \times 0.1$			
Package	TO8, TO66								
Acceptance angle Φ	$\sim 70^\circ$								
Window	wAl_2O_3				wZnSeAR				

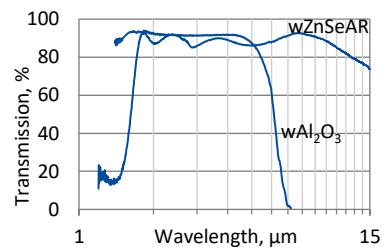
Four-stage thermoelectric cooler parameters

Parameter	Value
T_{det}, Kt	~195
V_{max}, V	8.3
I_{max}, A	0.4
Q_{max}, W	0.28

Thermistor characteristics

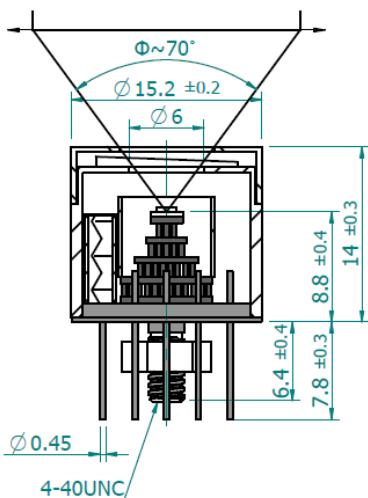


Spectral transmission of wAl₂O₃ and wZnSeAR windows (typical example)



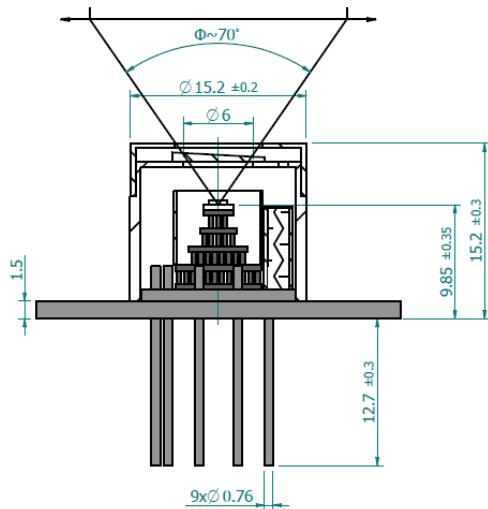
Mechanical layout, mm

4TE-T08 package



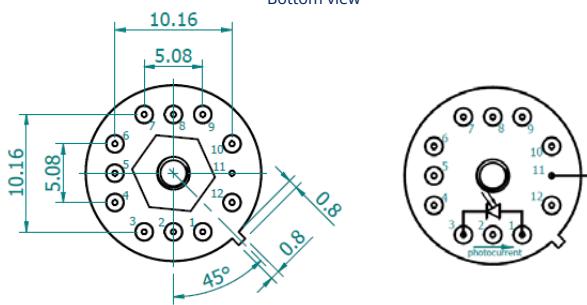
Φ – acceptance angle

4TE-TO66 package

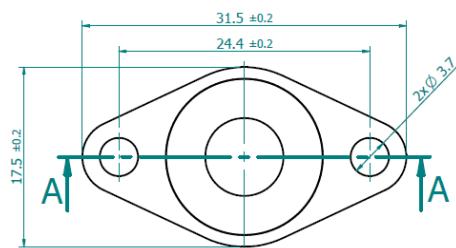


Φ = acceptance angle

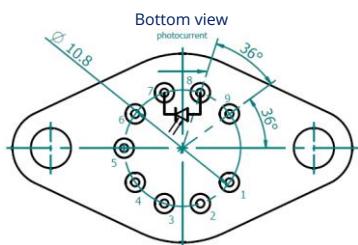
Bottom view



Top view



Bottom view



Function	Pin number
Detector	1, 3
Reverse bias (optional)	1(-), 3(+)
Thermistor	7, 9
TE cooler supply	2(+), 8(-)
Chassis ground	11
Not used	4, 5, 6, 10, 12

Function	Pin number
Detector	7, 8
Reverse bias (optional)	7(+), 8(-)
Thermistor	5, 6
TE cooler supply	1(+), 9(-)
Not used	2, 3, 4

Dedicated preamplifier



„all-in-one“ AIP



programmable PIP



standard MIP



small SIP-T08



fast FIP